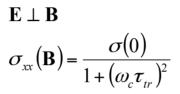
Magneto-transport in Weyl metals.

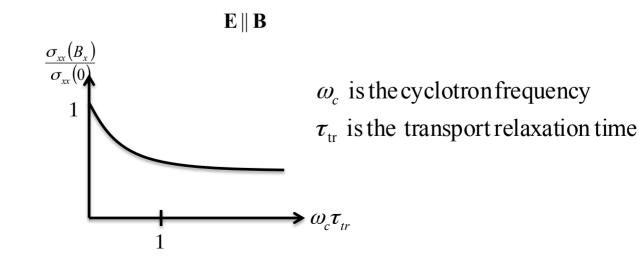
B.Spivak University of Washington

classical magnetoconductance of conventional metals and semiconductors

quasiclassical magnetoconductance is always negative



in the relaxation time approximation the longitudinal magnetoconductance is absent. Beyond this approximation it is negative and it saturates at $\omega_c \tau_{tr} > 1$



a generalization of the quasi-classical equations of motion for non centrosymmetric or not time reversal conductors. (Luttinger; Sundaram and Niu)

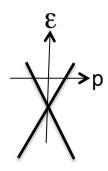
$$\frac{d\mathbf{r}}{dt} = \mathbf{v} + \left[\mathbf{\Omega}_{\mathbf{p}} \times \frac{d\mathbf{p}}{dt}\right]; \qquad \frac{d\mathbf{p}}{dt} = e\mathbf{E} + \frac{e}{c} \left[\frac{d\mathbf{r}}{dt} \times \mathbf{B}\right]$$

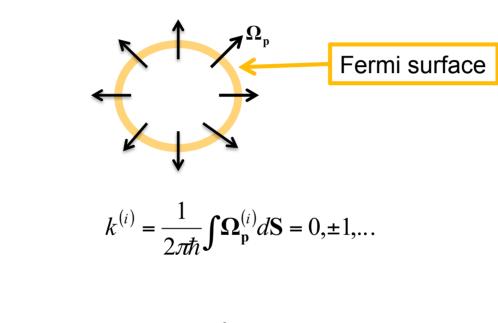
$$\frac{d\mathbf{r}}{dt} = \left(1 + \frac{e}{c}\mathbf{B}\cdot\mathbf{\Omega}_{\mathbf{p}}\right)^{-1} \left(\mathbf{v} + e\mathbf{E}\times\mathbf{\Omega}_{\mathbf{p}} + \frac{e}{c}\left(\mathbf{\Omega}_{\mathbf{p}}\cdot\mathbf{v}\right)\mathbf{B}\right)$$
$$\frac{d\mathbf{p}}{dt} = \left(1 + \frac{e}{c}\mathbf{B}\cdot\mathbf{\Omega}_{\mathbf{p}}\right)^{-1} \left(e\mathbf{E} + \frac{e}{c}\mathbf{v}\times\mathbf{B} + \frac{e^{2}}{c}(\mathbf{E}\cdot\mathbf{B})\mathbf{\Omega}_{\mathbf{p}}\right)$$

$$\begin{split} \boldsymbol{\Omega}_{\mathbf{p}} &= \nabla_{\mathbf{p}} \mathbf{A}_{\mathbf{p}}; \quad \mathbf{A}_{\mathbf{p}} = i \left\langle u_{\mathbf{p}} \mid \nabla_{\mathbf{p}} u_{\mathbf{p}} \right\rangle \\ \boldsymbol{\Omega}_{\mathbf{p}} &= -\boldsymbol{\Omega}_{-\mathbf{p}} \text{ in time reversal invariant systems} \\ \boldsymbol{\Omega}_{\mathbf{p}} &= \boldsymbol{\Omega}_{-\mathbf{p}} \text{ in centosymmetric systems} \\ \boldsymbol{\Omega}_{\mathbf{p}} &= 0 \quad \text{in centro - and time reversal symmetric systems} \\ \boldsymbol{u}_{\mathbf{p}}(\mathbf{r}) \text{ are Bloch wave functions} \end{split}$$

Berry curvature is divergence-free except at isolated points in the P-space, which are associated with band degeneracies.

$$\Omega_{\rm p} = curl \, A_{\rm p};$$





$$r_s = \frac{e^2}{\hbar v} \approx \frac{1}{10} << 1$$

at low magnetic field interactional corrections to the quasiclassical equations are small Quasiclassic description of electron transport in conventional metals and semiconductors

$$\frac{\partial f_{\mathbf{p}}(\mathbf{r},t)}{\partial t} + \dot{\mathbf{r}}\frac{\partial f_{\mathbf{p}}}{\partial \mathbf{r}} + \dot{\mathbf{p}}\frac{\partial f_{\mathbf{p}}}{\partial \mathbf{p}} = I_{st}\left\{f_{\mathbf{p}}\right\}$$

 I_{st} is the scattering integral characterized by intervalley scattering time τ

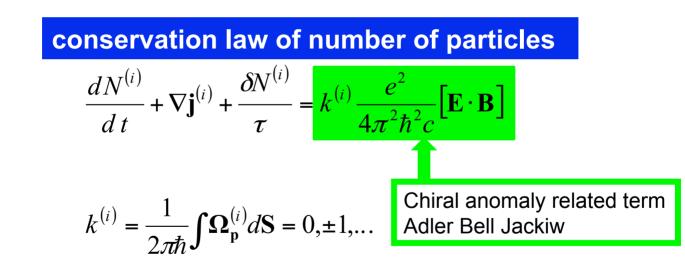
and intravalley scattering time $au_{ ext{intra}}$

1

a generalization of the kinetic equation

$$\frac{df_{\mathbf{p}}(\mathbf{r},t)}{dt} + \left(1 + \frac{e}{c}\mathbf{B}\cdot\mathbf{\Omega}_{\mathbf{p}}\right)^{-1} \left[\left(\mathbf{v} + e\mathbf{E}\times\mathbf{\Omega}_{\mathbf{p}} + \frac{e}{c}\left(\mathbf{\Omega}_{\mathbf{p}}\cdot\mathbf{v}\right)\mathbf{B}\right) \frac{df_{\mathbf{p}}}{d\mathbf{r}} + \left(e\mathbf{E} + \frac{e}{c}\mathbf{v}\times\mathbf{B} + \frac{e^{2}}{c}(\mathbf{E}\cdot\mathbf{B})\mathbf{\Omega}_{\mathbf{p}}\right) \frac{df_{\mathbf{p}}}{d\mathbf{p}} \right] = I_{st}(f_{\mathbf{p}})$$

$$N^{(i)} = \int d\mathbf{p} \left(1 + \frac{e}{c}\mathbf{B}\cdot\mathbf{\Omega}_{\mathbf{p}}^{(i)}\right) f_{\mathbf{p}}^{(i)}; \qquad \mathbf{j}^{(i)} = \int d\mathbf{p} \left[\mathbf{v} + e\mathbf{E}\times\mathbf{\Omega}_{\mathbf{p}}^{(i)} + \frac{e}{c}\left(\mathbf{\Omega}_{\mathbf{p}}^{(i)}\cdot\mathbf{v}\right)\mathbf{B}\right] f_{\mathbf{p}}^{(i)};$$



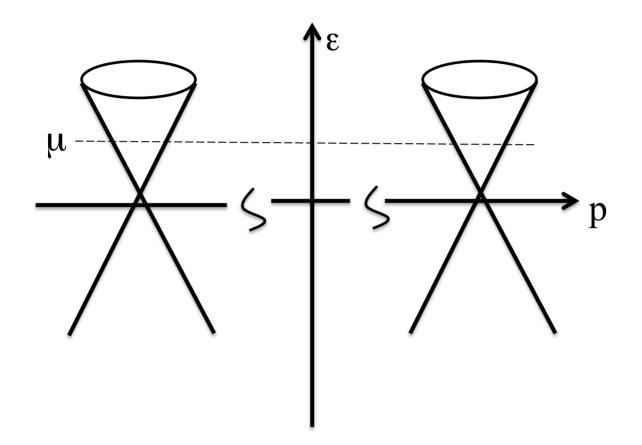
Quasiclassical kinetic equation captures effects of chiral anomaly

$$\int d\mathbf{p} \, \frac{d\varepsilon_{\mathbf{p}}}{d\mathbf{p}} \, f_{\mathbf{p}} \big(\varepsilon_{\mathbf{p}} \big) = 0$$

$$\mathbf{j}^{(i)} = \int d\mathbf{p} \, \frac{e}{c} \left(\mathbf{\Omega}_{\mathbf{p}}^{(i)} \cdot \mathbf{v} \right) \mathbf{B} f_{\mathbf{p}}^{(F)} == \mu \, k^{(i)} \mathbf{B}; \qquad \text{Vilenkin}$$

$$\mu^{(i)} = \mu, \qquad \sum_{i} k^{(i)} = 0; \qquad \mathbf{j} = \sum_{i} \mathbf{j}^{(i)} = 0;$$
Nielsen and Ninomiya theorem

Number of Weyl (massless Dirac) points should be even. (Nielsen and Ninomiya theorem)



Anomaly-related contribution to the conductivity corresponds to positive magnetoconductance

$$\delta \mu^{(i)} \propto \mathbf{E} \cdot \mathbf{B} \tau$$

$$\sigma_{zz}^{(an)} = N_D \frac{e^2}{4\pi^2 \hbar c} \frac{v}{c} \frac{(eB)^2 v^2}{\mu^2} \tau \quad \mu > T$$

$$\sigma_{ij}^{(an)} = 0 \quad i, j \neq z$$

au is the intervaley relaxation time

The current flows only in z-direction parallel to the magnetic field.

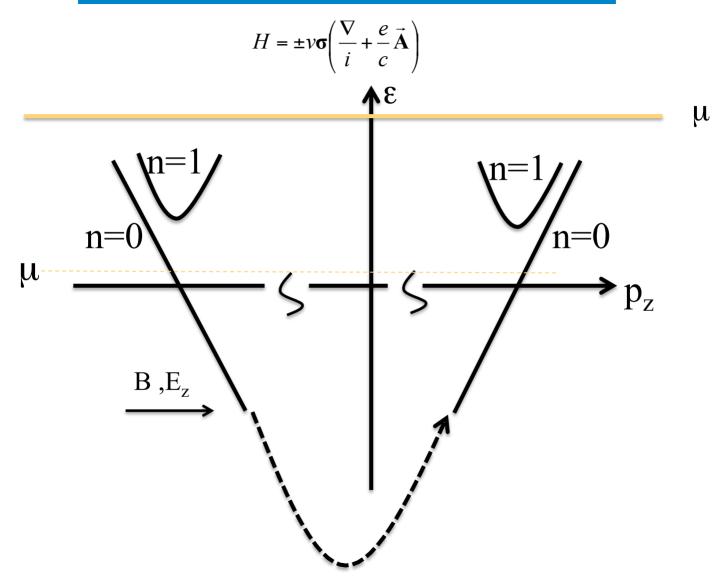
It responds only to z-component of the electric field.

Anomaly related contribution dominates magnetoresistance if the ratio between the interand intra-valley relaxation times is sufficiently large!

$$\frac{\tau}{\tau_{\text{intra}}} \frac{1}{(\mu \tau_{\text{intra}})^2} > 1 \qquad (\mu > T)$$

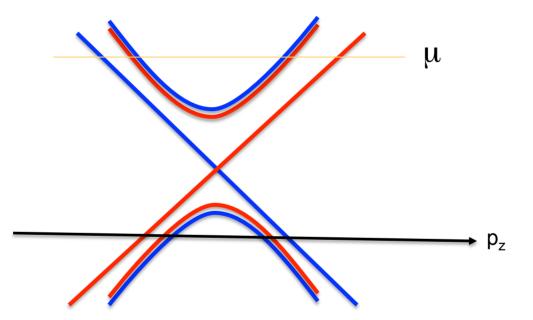
 τ and τ_{intra} are the intervaley and intravaley relaxation times resepctively

Electron spectrum in ultra-quantum limit



Electron spectrum of Dirac equation in magnetic field Akhiezer, Berestetzkii, "Quantum electrodynamics"

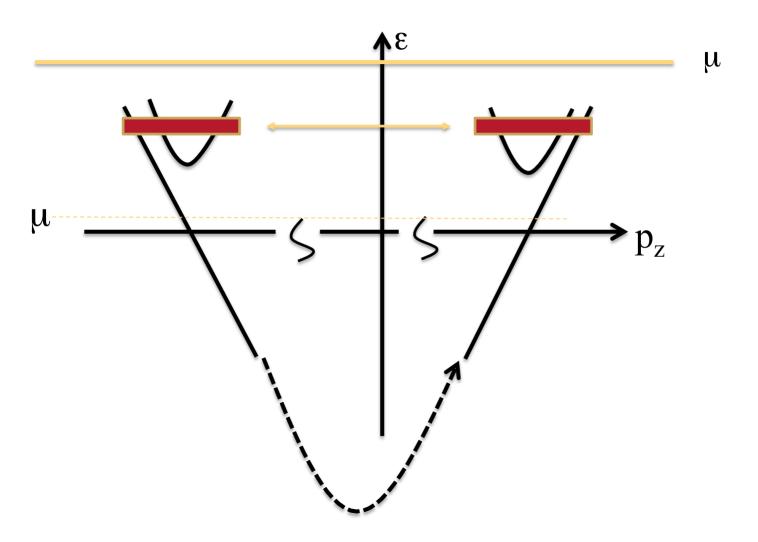
$$E_n^2 = p_z^2 + m^2 + |e|B(2n+1)|e|B\sigma$$



At m=0 there are two non-degenerate chiral levels.

Red and blue lines correspond to branches of spectrum with different helicities.

Einstein's relation between conductivity and diffusion coefficient

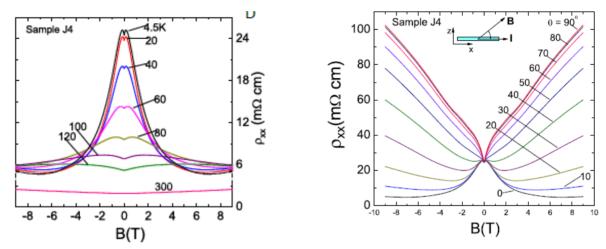


Signature of the chiral anomaly in a Dirac semimetal – a current plume steered by a magnetic field*

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(Dated: March 30, 2015)

Na₃Bi



Observation of the chiral magnetic effect in ZrTe₅

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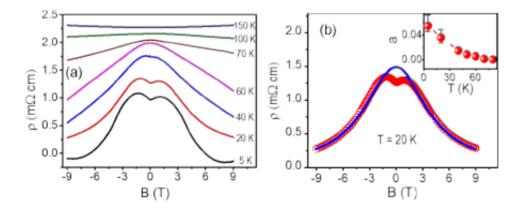
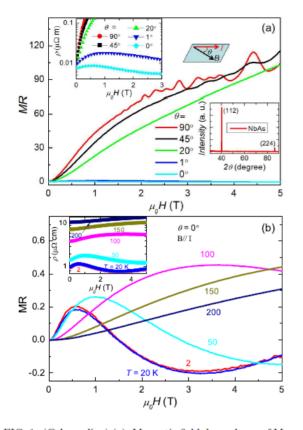


FIG. 2: Magnetoresistance in field parallel to current $(\vec{B} \parallel a)$ in ZrTe₅. (a) MR at various temperatures. For clarity, the resistivity curves were shifted by 1.5 mΩcm (150 K), 0.9 mΩcm (100 K), 0.2 mΩcm (70 K) and -0.2 mΩcm (5 K). (b) MR at 20K (red symbols) fitted with the CME curve (blue line); inset: temperature dependence of the fitting parameter a(T) in units of S/(cm T²).



bservation of Negative Magnetoresistance and nontrivial π Berrys phase in 3D Weyl semi-metal NbAs

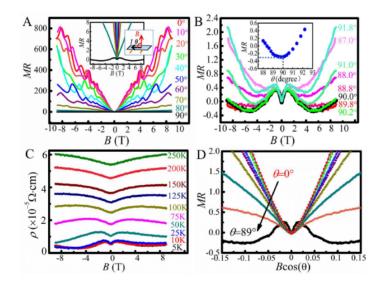
Xiaojun Yang,¹ Yupeng Li,¹ Zhen Wang,¹ Yi Zhen,^{1,2,*} and Zhu-an Xu^{1,2,†}

¹Department of Physics and State Key Laboratory of Silicon Materials, Zhejiang University, Hangzhou 310027, China ²Collaborative Innovation Centre of Advanced Microstructures, Nanjing 210093, P. R. China (Dated: June 9, 2015)

FIG. 1: (Color online) (a), Magnetic field dependence of Magnetoresistance with magnetic field $(\mu_0 H)$ from perpendicular $(\theta = 90^{\circ})$ to parallel $(\theta = 0^{\circ})$ to the electric current (I) at T = 2 K. The upper left inset displays the original resistivity data plotted on logarithmic scale, emphasizing the contrast between extremely large positive MR for magnetic field perpendicular to current $(\theta = 90^{\circ})$ and negative MR for field parallel to current $(\theta = 0^{\circ})$. The upper right inset depicts the corresponding measurement configurations. The lower inset present the single crystal XRD data. (b), Magnetic field dependence of MR under various temperatures for magnetic field $(\mu_0 H)$ parallel $(\theta = 0^{\circ})$ to the electric current (I). The inset display the original resistivity data.

Observation of the chiral anomaly induced negative magneto-resistance in 3D Weyl semi-metal TaAs

Xiaochun Huang^{1,§}, Lingxiao Zhao^{1,§}, Yujia Long¹, Peipei Wang¹, Dong Chen¹, Zhanhai Yang¹, Hui Liang¹, Mianqi Xue¹, Hongming Weng^{1,2}, Zhong Fang^{1,2}, Xi Dai^{1,2} and Genfu Chen^{1,2,*}

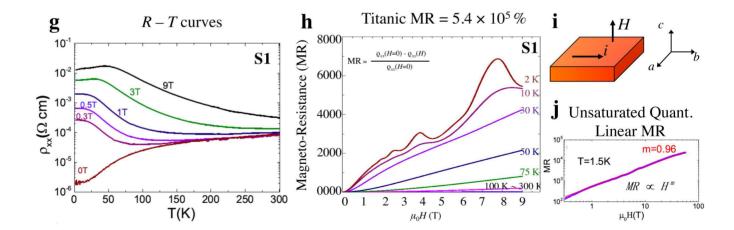


Figur 2: Angular and field dependence of MR in TaAs single crystal at 1.8 K. (A) Magneto-resistance with magnetic field (B) from perpendicular (θ =0°) to parallel (θ =90°) to the electric current (I). The inset zooms in on the lower MR part, showing negative MR at θ =90° (longitudinal negative MR), and depicts the correspondingly measurement configurations. (B) Magneto-resistance measured in different rotating angles around θ =90° with the interval of every 0.2°. The negative MR appeared at a narrow region around θ =90°, and most obviously when B//I. Either positive or negative deviations from 90° would degenerate and ultimately kill the negative MR in

Observation of the Adler-Bell-Jackiw chiral anomaly in a Weyl semimetal

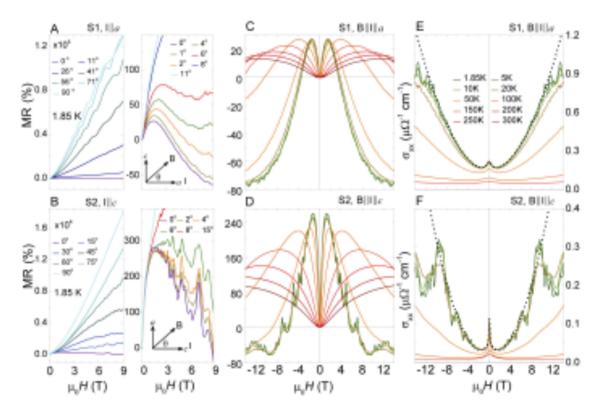
Chenglong Zhang^{*},¹ Su-Yang Xu^{*},^{2,3} Ilya Belopolski^{*},^{2,3} Zhujun Yuan^{*},¹ Ziquan Lin,⁴ Bingbing Tong,¹ Nasser Alidoust,² Chi-Cheng Lee,^{5,6} Shin-Ming Huang,^{5,6} Hsin Lin,^{5,6} Madhab Neupane,^{2,7} Daniel S. Sanchez,² Hao Zheng,² Guang Bian,² Junfeng

Wang,⁴ Chi Zhang,^{1,8} Titus Neupert,^{2,9} M. Zahid Hasan[†],^{2,3} and Shuang Jia^{†1,8}



Large and unsaturated negative magnetoresistance induced by the chiral anomaly in the Weyl semimetal TaP

Chandra Shekhar¹*, Frank Arnold¹*, Shu-Chun Wu¹, Yan Sun¹, Marcus Schmidt¹, Nitesh Kumar¹, Adolfo G. Grushin², Jens H. Bardarson², Ricardo Donizeth dos Reis¹, Marcel Naumann¹, Michael Baenitz¹, Horst Borrmann¹, Michael Nicklas¹, Elena Hassinger¹, Claudia Felser¹, & Binghai Yan^{1,2†}



Anomalous magnetoresistance in TaAs₂

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(Dated: January 22, 2016)

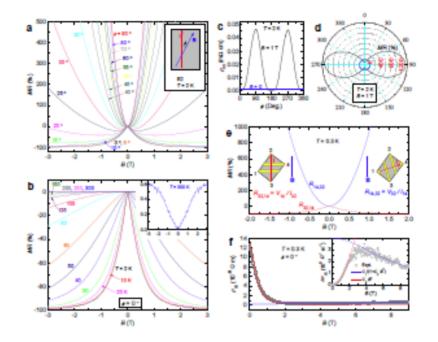


Figure 3 | Longitudinal magnetoresistance (LMR) of TaAs₂. a, Field-dependent MR of TaAs₂ with various angles ϕ at 2 K. The inset shows the configuration of the measurements. b, MR at different temperatures, measured at $\phi=0$. The inset displays the data at 300 K. c shows the angular dependence of ρ_{xx} at 2 K and 1 T. d is a polar plot of MR at 2 K. e shows the results with two different geometries, $R_{32,14}=V_{14}/I_{32}$ (red) and $R_{14,32}=V_{32}/I_{14}$ (blue). Schematic sketches of the geometry are shown in the insets. **f** presents theoretical fits of $\rho_{xx}(B)$ and $\Delta\sigma_{xx}(B)$. The high-field part of $\Delta\sigma_{xx}(B)$ is fit to $C_1/(1 + C_2B^2)$ (blue), while the low-field part is fit to C_3B^2 (red).

Why the parameter τ/τ_{intra} is so big in this experiments?

Conceptual and practical difficulties in ultra-quantum limit

1. B dependence of $\tau(B)$ is not universal.

For example in the case of short range impurities $\frac{1}{\tau} \propto \frac{1}{L_B^2}$ is proportional to the density of states and σ_{zz} is independent on B

2. It is dificult to distinguish chiral anomaly related magnetoresistance from magnetoresistance in conventional conductors in ultra – quantum magnetic field

3. At T = 0 the system is unstable with respect to charge density wave. In this case chiral anomaly does not exist Temperature gradient does not pump either electrons or energy between valleys with different chiralities! So the magnetetic field dependence of the thermoelectric effect has nothing to do with any



 T_1

 τ_{ϵ}



Х

Thermal conductivity

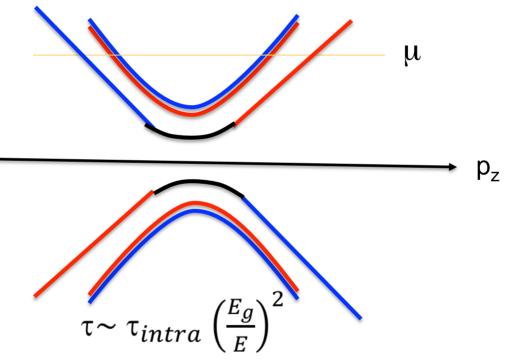
$$\kappa_{zz} = \frac{\pi^2 \sigma_{zz}^{(an)} T}{3e^2} \frac{\tau_{\varepsilon}}{\tau_{\varepsilon} + \tau}$$

Thermoelectric coefficient

$$\eta_{zz} = \frac{\pi^2}{3e^2} T \frac{d\sigma_{zz}^{(an)}}{d\mu} \frac{\tau_{\varepsilon}}{\tau_{\varepsilon} + \tau}$$

All effects which have been observed in Weyl metals are allowed by symmetry. So it is only a question of finding a proper relation between parameters which will lead to explanation of observables. semiconductors with sufficiently small gaps and sufficiently large chemical potential should have magnetic field dependence of kinetic coefficients which are similar to those in Weyl and Dirac metals

Spectrum of Dirac equation at finite mass



what about other mechanisms of negative parallel magnetoresistance?

NEGATIVE LONGITUDINAL MAGNETORESISTANCE ASSOCIATED WITH SCATTERING FROM IONIZED IMPURITY CENTERS

L. S. DUBINSKAYA

Semiconductor Institute, Academy of Sciences, U.S.S.R. Submitted October 28, 1968 Zh. Eksp. Teor. Fiz. 56, 801-812 (March, 1969)

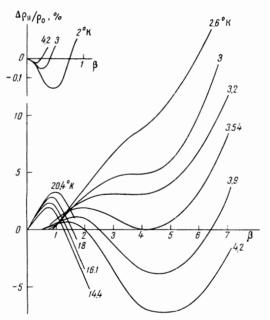


FIG. 3. Experimental dependences of the magnetoresistance $\Delta \rho_{\parallel} / \rho$ on β at different temperatures. Initial segments of some curves, representing amplified measurements, are shown in the upper left-hand corner.

